rohm

- ♦ STRUCTURE
- ♦ PRODUCT Microwire BUS Serial EEPROMs
- ♦ SERIES SIGNATURE SERIES
- ♦ FAMILY BR93C□□ family
- ♦ TYPE

Supply voltage 4.5V \sim 5.5V/Opreating temperature -40°C \sim +105°Ctype

Silicon Monolithic Integrated Circuit

♦ PART NUMBER BR93C□□-□□□7TP

PART NUMBER	PACKAGE	DENSITY
BR93C46- MN7TP		1Kbit
BR93C56- MN7TP		2Kbit
BR93C66- MN7TP	SO8 narrow	4Kbit
BR93C76- MN7TP		8Kbit
BR93C86- MN7TP		16Kbit
BR93C46-TMN7TP		1Kbit
BR93C56-TMN7TP	SO8 narrow	2Kbit
BR93C66-TMN7TP	(different pin assignment)	4Kbit
BR93C76-TMN7TP	(different pin assignment)	8Kbit
BR93C86-TMN7TP		16Kbit

♦ FEATURES

Microwire BUS interface Endurance : 1,000,000 erase/write cycles Data retention : 40 years Intial Data FFFFh in all address

♦ ABSOLUTE MAXIMUM RATINGS

Symbol Parameter		Min.	Max.	Unit
Т _{stg}	Storage Temperature	-65	125	°C
V _{OUT}	Output Range(Q=V _{OH} or Hi-Z)	-0.3	Vcc+0.3	V
V _{IN}	Input range	-0.3	Vcc+0.3	V
V _{cc}	Supply Voltage	-0.3	6.5	V

♦ POWER DISSIPATION (Ta=25°C)

PACKAGE	Rating	Unit
SO8 narrow	450 *1	mW

* Degradation is done at $4.5 \text{mW/}^{\circ}\text{C}(*1)$ for operation above 25°C

1/4

rohm

♦ RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{cc}	Supply Voltage	4.5	5.5	v
T _A	Ambient Operating Temperature	-40	105	°C

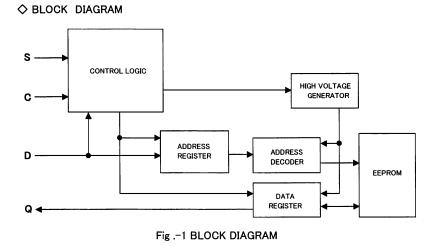
\diamondsuit DC OPERATING CHARACTERISTICS

(Unless otherwise specified, Ta=-40~105°C, Vcc=4.5~5.5V)								
Parameter	Symbol	Specification				T 10 IV		
		Min.	Тур.	Max.	Unit	Test Condition		
Input Leakage Current	IL1	-	-	±2.5	μA	0V≦V _{IN} ≦Vcc		
Output Leakage Current	۲,	-	-	±2.5	μA	0V≦V _{out} ≦Vcc, Q in Hi∽Z		
Supply Current (CMOS Inputs)	I _{cc}	-	-	2	mA	Vcc=5V,S=V _{IH} ,f=2MHz		
Supply Current(Stand-by)	I _{CC1}	-	-	15	μA	Vcc=2.5V,S=Vss,C=Vss		
Input Low Voltage(D,C,S)	Vil	-0.3	-	0.8	v			
Input High Voltage(D,C,S)	V _{IH}	2	-	Vcc+0.3	v			
Output Low Voltage(Q)	V _{OL}	-	-	0.4	v	Vcc=5V,I _{OL} =2.1mA		
Output High Voltage(Q)	V _{OH}	2.4	-	-	v	Vcc=5V.I _{OH} =-400 <i>µ</i> А		

♦ AC OPERATING CHARACTERISTICS

(Unless otherwise specified, Ta=-4		Sp	pecificati		
Parameter	Symbol	Min.	Тур.	Max.	Unit
Clock Frequency	fc	D.C	-	2	MHz
Chip Select Low to Clock High	t _{slCH}	50	-	-	ns
Chip Select Set-up Time	t _{SHCH}	50	-	-	ns
Chip Select Low to Chip Select High	t _{SLSH}	200	-	-	ns
Clock High Time	t _{CHCL} *1	200	-	-	ns
Clock Low Time	t _{CLCH} *1	200	-	-	ns
Data In Set-up Time	t _{ovch}	50	-	-	ns
Data In Hold Time	t _{CHDX}	50	-	-	ns
Clock Set-up Time(relative to S)	t _{CLSH}	50	-	-	ns
Chip Select Hold Time	t _{clsl}	0	1	-	ns
Chip Select to Ready/Busy Status	t _{shav}	1	-	200	ns
Chip Select Low to Output Hi-Z	t _{SLQZ}	1	-	100	ns
Delay to Output Low	t _{CHQL}	-	-	200	ns
Delay to Output Valid	t _{chav}	-	-	200	ns
Erase/Write Cycle time	tw	-	-	5	ms

*1 t_{CHCL}+t_{CLCH}≧1/f_C



♦ PIN No., PIN NAME

PIN No.	PIN NAME		
1	S	DU	
2	с	Vcc	
3	D	s	
4	Q	С	
5	Vss	D	
6	DU	Q	
7	DU	Vss	
8	Vcc	DU	
	BR93C46-MN7TP	BR93C46-TMN7TF	
	BR93C56-MN7TP	BR93C56-TMN7TF	
PART NUMBER	BR93C66-MN7TP	BR93C66-TMN7TF	
	BR93C76-MN7TP	BR93C76-TMN7TF	
	BR93C86-MN7TP	BR93C86-TMN7TF	



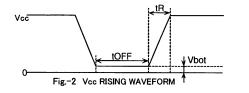
♦ NOTES FOR POWER SUPPLY

This IC has a POR (Power On Reset) circuit as mistake write countermeasure.

After POR action, it gets in write disable status. The POR circuit is valid only when power is ON, and does not work when power is OFF. However, if S is "H" at power ON/OFF, it may become write enable status owing to noises and the likes. For secure operations, observe the following conditions.

1. Set S = "L".

2. Turn on power so as to satisfy the recommended conditions of tR, tOFF, Vbot for POR circuit operation.



Recommended conditions of tR, tOFF, Vbot				
tR tOFF		Vbot		
Below 10ms	Above 10ms	Below 0.3V		
Below 100ms	Above 10ms	Below 0.2V		

♦ CAUTIONS ON USE

(1) Absolute maximum ratings

If the absolute maximum ratings such as impressed voltage and action temperature range and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.

(2) Vss electric potential

Set the voltage of Vss terminal lowest at any action condition. Make sure that each terminal voltage is lower than that of Vss terminal.

(3) Thermal design

In consideration of permissible loss in actual use condition, carry out heat design with sufficient margin.

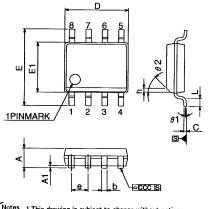
(4) Terminal to terminal shortcircuit and wrong packaging

When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of shortcircuit between LSI terminals and terminals and power source, terminal and Vss owing to foreign matter, LSI may be destructed.

(5) Use in a strong electromagnetic field may cause malfunction, therefore, evaluated design sufficiently.

Rohm

♦ PHYSICAL DIMENSION



♦ SO8 narrow Package size data mm inches Symb. Min. Тур. Max. Тур. Min. Max. А 1.35 -1.75 0.053 -0.069 A1 0.10 -0.25 -0.004 0.010 b 0.013 --0.33 0.51 -0.020 -0.19 с 0.25 0.007 0.010 D -4.80 5.00 _ 0.189 0.197 е 1.27 -_ 0.05 --Е -5.80 6.20 0.228 0.244 -E1 3.80 4.00 _ 0.150 0.157 L _ 0.40 1.27 0.05 0.016 0.050 θ1 -0° 8° 0° _ 8° -ccc 0.10 _ 0.004 1 0.25 h 0.50 -0.010 0.020 45° θ2 -45° ---

Notes 1.This drawing is subject to change without notice. 2.Body dimensions do not include mold flash or protrusion, or gate burns. 3.Reference JEDEC MS-012 variation AA.

Fig.-3 SO8 narrow Package Outline

REV.A

4/4

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

rohm

Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact your nearest sales office.

Please contact our sales offices for details ;

U.S.A / San Diego Atlanta Dallas	TEL : +1(858)625-3630 TEL : +1(770)754-5972 TEL : +1(972)312-8818	FAX : +1(858)625-3670 FAX : +1(770)754-0691 FAX : +1(972)312-0330	
Germany / Dusseldorf	TEL : +49(2154)9210	FAX : +49(2154)921400	
United Kingdom / London	TEL : +44(1)908-282-666	FAX : +44(1)908-282-528	
France / Paris	TEL : +33(0)1 56 97 30 60	FAX : +33(0) 1 56 97 30 80	
China / Hong Kong Shanghai Dilian Beijing	TEL : +852(2)740-6262 TEL : +86(21)6279-2727 TEL : +86(411)8230-8549 TEL : +86(10)8525-2483	FAX : +852(2)375-8971 FAX : +86(21)6247-2066 FAX : +86(411)8230-8537 FAX : +86(10)8525-2489	
Taiwan / Taipei	TEL : +866(2)2500-6956	FAX : +866(2)2503-2869	
Korea / Seoul	TEL : +82(2)8182-700	FAX : +82(2)8182-715	
Singapore	TEL : +65-6332-2322	FAX : +65-6332-5662	
Malaysia / Kuala Lumpur	TEL : +60(3)7958-8355	FAX : +60(3)7958-8377	
Philippines / Manila	TEL : +63(2)807-6872	FAX : +63(2)809-1422	
Thailand / Bangkok	TEL : +66(2)254-4890	FAX : +66(2)256-6334	

lanan /

Japan / (Internal Sales	5)
Tokyo	2-1-1, Yaesu, Chuo-ku, Tokyo 104-0082 TEL : +81(3)5203-0321
Yokohama	2-4-8, Shin Yokohama, Kohoku-ku, Yokohama, Kanagawa 222-8575 TEL : +81(45)476-2131 FAX : +81(45)476-2128
Nagoya	Dainagayo Building 9F 3-28-12, Meieki, Nakamura-ku, Nagoya, Aichi 450-0002 TEL : +81(52)581-8521 FAX : +81(52)561-2173
Kyoto	579-32 Higashi Shiokouji-cho, Karasuma Nishi-iru, Shiokoujidori, Shimogyo-ku, Kyoto 600-8216 TEL : +81(75)311-2121 FAX : +81(75)314-6559
(Contact addre	ess for overseas customers in Japan)
Yokohama	TEL : +81(45)476-9270 FAX : +81(045)476-9271

As of 18th. April 2005